Chip Monolithic Ceramic Capacitors

muRata

for Ultrasonic Sensors

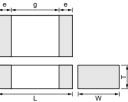
Features

- 1. Proper compensation for ultrasonic sensors
- 2. Small chip size and high capacitance value

Application

Ultrasonic sensor (back sonar, corner sonar, etc.)





Part Number	Dimensions (mm)					
Part Number	L	W	Т	е	g min.	
GRM219	2.0 ±0.1	1.25 ±0.1	0.85 ±0.1	0.2 to 0.7	0.7	

Part Number	TC Code	Rated Voltage (Vdc)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM2199E2A102KD42	ZLM (Murata)	100	1000 ±10%	2.0	1.25	0.85
GRM2199E2A152KD42	ZLM (Murata)	100	1500 ±10%	2.0	1.25	0.85



Specifications and Test Methods

No.	Item	Item Specifications		Test Method					
1	Operating Temperature		-25℃ to +85℃						
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, $V^{P,P}$ or $V^{O,P}$, whichever is larger, should be maintained within the rated volt- age range.					
3	Appearance		No defects or abnormalities	Visual inspection.	inspection.				
4	Dimensions		Within the specified dimensions	Using calipers.					
5	Dielectric Stren	ngth	No defects or abnormalities	is applied between	e observed when 300% of the rated voltage the terminations for 1 to 5 seconds, provid- narge current is less than 50mA.				
6	Insulation Resista (I.R.)	ance	More than 10,000M Ω or 500 Ω • F. (Whichever is smaller)	The insulation resistance should be measured with a DC volt- age not exceeding the rated voltage at 20°C and 75%RH max. and within 2 minutes of charging.					
7	Capacitance		Within the specified tolerance		E should be massured at 20°C with				
8	Dissipation Fact (D.F.)	tor	0.01 max.	 The capacitance/D.F. should be measured at 20°C with 1±0.1kHz in frequency and 1±0.2Vr.m.s. in voltage. 					
9	Capacitance 9 Temperature	Within $-4,700 \pm 1.868 \text{ ppm/°C}$ (at $-25 \text{ to } \pm 20°\text{C}$)	The temperature coefficient is determined using the capacitance measured in step 1 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient. The capacitance change should be measured after 5 min. at each specified temperature stage.						
,	Characteristics		Within −4,700 ^{±500} _{1.000} ppm/°C (at +20 to +85°C)	Step1	Temperature(°C)				
				2	20±2 -25±3				
				3	20±2				
				4	85±3				
				5	20±2				
10	Adhesive Stren of Termination	gth	No removal of the terminations or other defect should occur.	Fig.1 using a eutec direction of the arro The soldering shou reflow method and	r to the test jig (glass epoxy board) shown in tic solder. Then apply 10N force in the w. Id be done either with an iron or using the should be conducted with care so that the n and free of defects such as heat shock.				
				Fig.1					
	Appear		No defects or abnormalities		r to the test jig (glass epoxy board) in the under the same conditions as (10).				
11	Vibration Resistance D.F.	tance	Within the specified tolerance 0.01 max.	 The capacitor shou having a total ampli uniformly between frequency range, fre be traversed in app 	Id be subjected to a simple harmonic motion itude of 1.5mm, the frequency being varied the approximate limits of 10 and 55Hz. The om 10 to 55Hz and return to 10Hz, should proximately 1 minute. This motion should be of 2 hours in each of 3 mutually perpendic-				

Continued on the following page.

9



Specifications and Test Methods

Continued from the preceding page.

۱o.	Ite	m	Specifications	Test Method								
12	2 Deflection		No cracking or marking defects should occur. t = 1.6 mm	Solder the capacitor to the test jig (glass epoxy boards) show in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.								
			Type a b c GRM21 1.2 4.0 1.65 (in mm) Fig. 2	Capacitance meter 45 45 (in mm) Fig.3								
13	Solderabi Terminati	2	75% of the terminations are to be soldered evenly and continuously	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5°C.								
		Appearance	No defects or abnormalities	Preheat the capacitor at 120 to 150°C for 1 minute. Immerse th capacitor in a eutectic solder solution at 270±5°C for 10±0.5 seconds. Let sit at room temperature for 24±2 hours, then								
Re	Resistance	Capacitance Change	Within ±7.5%									
4	to Soldering Heat	D.F.	0.01 max.									
		I.R.	More than 10,000M Ω or 500 Ω • F (Whichever is smaller)	smaller) measure.								
	Dielectric Strength		No failure									
		Appearance	No defects or abnormalities	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room tem-								
	Temperature	Capacitance Change	Within ±7.5%									
15	Cycle	D.F.	0.01 max.	perature, then		2	2	4				
	-	I.R.	More than 10,000M Ω or 500 Ω • F (Whichever is smaller)	Step Temp. (°C)	1 -25±3	2 RoomTemp.	3 85 ⁺³	4 RoomTemp.				
		Dielectric Strength	No failure	Time (min.)	30±3	2 to 3	30±3	2 to 3				
		Appearance	No defects or abnormalities	_								
Humidity,	Capacitance Change	Within ±12.5%	Sit the capacitor at 40±2°c and 90 to 95% humidity for 500±1									
			0.02 max.	hours. Remove and let sit for 24 ± 2 hours at room temperature, then								
6	Steady	D.F.		Remove and le	et Sit 101 24	±2 nouis at i	•	measure.				
16		I.R. Dielectric	More than 1,000M Ω or 50 Ω • F (Whichever is smaller)		et Sit 101 24							
6	Steady	I.R. Dielectric Strength	More than 1,000M Ω or 50 Ω • F (Whichever is smaller) No failure									
6	Steady	I.R. Dielectric Strength Appearance	More than 1,000M Ω or 50 Ω • F (Whichever is smaller)	measure.				humidity for				
	Steady	I.R. Dielectric Strength Appearance Capacitance Change	More than 1,000M Ω or 50 Ω • F (Whichever is smaller) No failure No defects or abnormalities Within ±12.5%		l voltage a Remove a	t 40±2℃ and and let sit for	90 to 95% 24±2 hour	s at room terr				
	Steady State Humidity	I.R. Dielectric Strength Appearance Capacitance Change D.F.	More than 1,000MΩ or 50Ω • F (Whichever is smaller) No failure No defects or abnormalities Within ±12.5% 0.02 max.	Apply the rated 500±12 hours.	l voltage a Remove a	t 40±2℃ and and let sit for	90 to 95% 24±2 hour	s at room ten				
	Steady State Humidity	I.R. Dielectric Strength Appearance Capacitance Change D.F. I.R.	More than 1,000M Ω or $50\Omega \cdot F$ (Whichever is smaller) No failure No defects or abnormalities Within $\pm 12.5\%$ 0.02 max. More than 500M Ω or $25\Omega \cdot F$ (Whichever is smaller)	Apply the rated 500±12 hours. perature, then	l voltage a Remove a	t 40±2℃ and and let sit for	90 to 95% 24±2 hour	s at room ten				
16	Steady State Humidity Load	I.R. Dielectric Strength Appearance Capacitance Change D.F. I.R. Appearance Capacitance	More than 1,000MΩ or 50Ω • F (Whichever is smaller) No failure No defects or abnormalities Within ±12.5% 0.02 max.	Apply the rated 500±12 hours. perature, then than 50mA.	I voltage a Remove a measure.	t 40±2℃ and and let sit for The charge/d voltage for 1,	90 to 95% 24±2 hour ischarge c 000±12 hc	s at room terr urrent is less ours at 85±3℃				
	Steady State Humidity Load	I.R. Dielectric Strength Appearance Capacitance Change D.F. I.R. Appearance	More than 1,000M Ω or 50 Ω • F (Whichever is smaller) No failure No defects or abnormalities Within ±12.5% 0.02 max. More than 500M Ω or 25 Ω • F (Whichever is smaller) No defects or abnormalities	Apply the rated 500±12 hours. perature, then than 50mA.	I voltage a Remove a measure. 7 the rated 2 hours at	t 40±2℃ and and let sit for The charge/d voltage for 1, room tempera	90 to 95% 24±2 hour ischarge c 000±12 ho ature, then	s at room terr urrent is less ours at 85±3°C measure.				

